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## FACSIMILE COVER SHEET

To: Examiner Thanh Y. Tran	Total Pages Sent: 14
Technology Center 2800	(including cover sheet)
Facsimile Number: (571) 273-8300	Transmission Date: April 10, 2006

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Haupt Docket No.: INTECH 3.0-104  
(2003 P 51718 US)

Serial No: 10/766,053 Art Unit: 2822

Date Filed: January 28, 2004

Title: Method for N+ Doping of Amorphous Silicon and Polysilicon Electrodes in Deep Trenches

## CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that the following papers are being transmitted by facsimile to the U.S. Patent and Trademark Office at (571) 273-8300 on the date shown above:

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- Amendment (10 pages)
- Information Disclosure Statement (2 duplicate pages)
- PTO/SB08a with one reference cited (1 page)

Respectfully submitted,

Theresa O'Connor  
Legal Assistant

Confirmation Respectfully Requested

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